MDO500-14N1

| $\mathrm{V}_{\text {RRM }}$ | $=1400 \mathrm{~V}$ |
| :--- | :--- |
| $\mathrm{I}_{\text {FAV }}$ | $=560 \mathrm{~A}$ |
| $\mathrm{~V}_{\mathrm{F}}$ | $=0.98 \mathrm{~V}$ |

## Single Diode

## Part number

## MDO500-14N1



NㅔN2873


## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour


## Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling


## Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

| Rectifier |  |  |  | Ratings |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Definition | Conditions |  | min. | typ. | max. | Unit |
| $\mathrm{V}_{\text {RSM }}$ | max. non-repetitive reverse blocking voltage |  | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 1500 | V |
| $\mathrm{V}_{\text {RRM }}$ | max. repetitive reverse blocking voltage |  | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 1400 | V |
| $\mathrm{I}_{\mathrm{R}}$ | reverse current | $\mathrm{V}_{\mathrm{R}}=1400 \mathrm{~V}$ | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 1 | mA |
|  |  | $\mathrm{V}_{\mathrm{R}}=1400 \mathrm{~V}$ | $\mathrm{T}_{\mathrm{v},}=140^{\circ} \mathrm{C}$ |  |  | 30 | mA |
| $\overline{\mathrm{V}}$ | forward voltage drop | $\mathrm{I}_{\mathrm{F}}=500 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  |  | 1.09 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=1000 \mathrm{~A}$ |  |  |  | 1.24 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=500 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{v},}=125^{\circ} \mathrm{C}$ |  |  | 0.98 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=1000 \mathrm{~A}$ |  |  |  | 1.17 | V |
| $\mathrm{I}_{\text {fav }}$ | average forward current RMS forward current | $\mathrm{T}_{\mathrm{C}}=85^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{v} J}=140^{\circ} \mathrm{C}$ |  |  | 560 | A |
| $\mathrm{I}_{\text {F(RMS) }}$ |  | $180^{\circ}$ sine $\quad d=0.5$ |  |  |  |  | A |
| $\mathrm{V}_{\mathrm{F} 0}$ | $\left.\begin{array}{l} \text { threshold voltage } \\ \text { slope resistance } \end{array}\right\} \text { for power loss calculation only }$ |  | $\mathrm{T}_{\mathrm{v},}=140^{\circ} \mathrm{C}$ |  |  | 0.80 | V |
| $\mathrm{r}_{\mathrm{F}}$ |  |  | 0.38 |  |  | $\mathrm{m} \Omega$ |
| $\mathbf{R}_{\text {thJc }}$ | thermal resistance junction to case |  |  |  |  |  | 0.072 | K/W |
| $\mathbf{R}_{\text {tnch }}$ | thermal resistance case to heatsink |  |  |  | 0.024 |  | K/W |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation |  | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  |  | 1600 | W |
| $\mathrm{I}_{\text {FSM }}$ | max. forward surge current | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{v} \delta}=45^{\circ} \mathrm{C}$ |  |  | 15.0 | kA |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 16.2 | kA |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{vJ}}=140^{\circ} \mathrm{C}$ |  |  | 12.8 | kA |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 13.8 | kA |
| $1{ }^{2} \mathrm{t}$ | value for fusing | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{v} \mathrm{s}}=45^{\circ} \mathrm{C}$ |  |  | 1.13 | $M^{2}{ }^{2}$ |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 1.09 | MA ${ }^{2}$ s |
|  |  | $\mathrm{t}=10 \mathrm{~ms}$; $(50 \mathrm{~Hz})$, sine | $\mathrm{T}_{\mathrm{v} ~}=140^{\circ} \mathrm{C}$ |  |  | 812.8 | $k^{2}{ }^{2} \mathrm{~s}$ |
|  |  | $\mathrm{t}=8,3 \mathrm{~ms} ;(60 \mathrm{~Hz})$, sine | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  |  | 788.8 | $\mathrm{kA}^{2} \mathrm{~s}$ |
| $\mathrm{C}_{\text {J }}$ | junction capacitance | $\mathrm{V}_{\mathrm{R}}=400 \mathrm{~V} ; \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{T}_{\mathrm{v},}=25^{\circ} \mathrm{C}$ |  | 762 |  | pF |


| Package | Y1 |  | Ratings |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Symbol | Definition Conditions |  | min. | typ. | max. | Unit |
| $\mathrm{I}_{\text {RMS }}$ | RMS current per terminal |  |  |  | 600 | A |
| $\mathrm{T}_{\mathrm{vj}}$ | virtual junction temperature |  | -40 |  | 140 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {op }}$ | operation temperature |  | -40 |  | 125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -40 |  | 125 | ${ }^{\circ} \mathrm{C}$ |
| Weight |  |  |  | 650 |  | g |
| $\begin{aligned} & \mathbf{M}_{\mathrm{D}} \\ & \mathbf{M}_{\mathrm{T}} \end{aligned}$ | mounting torque terminal torque |  | $\begin{array}{r} 4.5 \\ 11 \end{array}$ |  | 7 13 | Nm Nm |
| $\mathbf{d}_{\text {Spp/App }}$ $\mathbf{d}_{\text {spb/Apb }}$ | creepage distance on surface / striking distance through air | terminal to terminal terminal to backside | $\begin{aligned} & 16.0 \\ & 25.0 \end{aligned}$ |  |  | $\begin{aligned} & \mathrm{mm} \\ & \mathrm{~mm} \end{aligned}$ |
| $\mathrm{V}_{\text {ISOL }}$ | isolation voltage $\quad \begin{aligned} & \mathrm{t}=1 \text { second } \\ & \mathrm{t}=1 \text { minute }\end{aligned}$ | $50 / 60 \mathrm{~Hz}, \mathrm{RMS}$; lisol $\leq 1 \mathrm{~mA}$ | $\begin{aligned} & 3600 \\ & 3000 \end{aligned}$ |  |  | V V |



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.\# (26-31), blank (32), serial no.\# (33-36)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Standard | MDO500-14N1 | MDO500-14N1 | Box | 2 | 464805 |


| Similar Part | Package | Voltage class |
| :--- | :--- | :---: |
| MDO500-12N1 | Y1-2-CU | 1200 |
| MDO500-16N1 | Y1-2-CU | 1600 |
| MDO500-18N1 | Y1-2-CU | 1800 |
| MDO500-20N1 | Y1-2-CU | 2000 |


| MDO500-22N1 | Y1-2-CU | 2200 |
| :--- | :--- | :---: |

## Equivalent Circuits for Simulation *on die level $\quad \mathrm{T}_{\mathrm{vJ}}=140^{\circ} \mathrm{C}$

|  |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{0 \text { max }}$ | threshold voltage | 0.8 | V |
| $\mathbf{R}_{0 \text { max }}$ | slope resistance * | 0.19 | $\mathrm{m} \Omega$ |

Outlines


## Rectifier



Fig. 1 Surge overload current $\mathrm{I}_{\text {FSM }}$ : Crest value, t : duration


Fig. $2 I^{2} \mathrm{t}$ versus time ( $1-10 \mathrm{~ms}$ )


Fig. 4 Power dissipation vs. forward current and ambient temperature


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature. $R=$ resistive load, $L=$ inductive load

## Rectifier



Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature


Fig. 7 Transient thermal impedance junction to case

$\mathrm{R}_{\text {thJk }}$ for various conduction angles d :

| d | $\mathrm{R}_{\mathrm{thJK}}(\mathrm{K} / \mathrm{W})$ |
| :--- | :--- |
| DC | 0.096 |
| $180^{\circ}$ | 0.1 |
| $120^{\circ}$ | 0.105 |
| $60^{\circ}$ | 0.116 |
| $30^{\circ}$ | 0.135 |

Constants for $\mathrm{Z}_{\text {thJK }}$ calculation:

| i | $\mathrm{R}_{\mathrm{thi}}(\mathrm{K} / \mathrm{W})$ | $\mathrm{t}_{\mathrm{i}}(\mathrm{s})$ |
| :--- | :--- | :--- |
| 1 | 0.0035 | 0.0054 |
| 2 | 0.0186 | 0.098 |
| 3 | 0.0432 | 0.54 |
| 4 | 0.0067 | 12 |
| 5 | 0.024 | 12 |

Fig. 8 Transient thermal impedance junction to heatsink

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for Discrete Semiconductor Modules category:
Click to view products by IXYS manufacturer:

Other Similar products are found below :

| M252511FV | DD260N12K-A | DD380N16A | DD89N1600K | APT2X21D | C60J APT58M | 80J B522F-2-Y | EEC MSTC90-16 | 1625.163 | 3.0653 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 25.163.2453.0 | 25.163.4253.0 | 25.190.2053.0 | 25.194.3453.0 | 25.320.4853.1 | 25.320.5253.1 | 25.326.3253.1 | 25.326.3553.1 | 25.330.1 | 1653.1 |
| 25.330.4753.1 | 25.330.5253.1 | 25.334.3253.1 | 25.334.3353.1 | 25.350.2053.0 | 25.352.4753.1 | 25.522.3253.0 | T483C T484C | T485F | T485 |
| T512F-YEB | T513F T514F | T554 T612FSE | 25.161.3453.0 | 25.179.2253.0 | 25.194.3253.0 | 25.325.1253.1 | 25.326.4253.1 | 25.330.0 | 0953.1 |
| 25.332.4353.1 | 25.350.1653.0 | 25.350.2453.0 | 25.352.1453.0 | 25.352.1653.0 | 25.352.2453.0 | 25.352.5453.1 | 25.522.3353.0 | 25.602.4 | 4053.0 |
| 25.640.5053.0 |  |  |  |  |  |  |  |  |  |

